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AD7534—SPECIFICATIONS¹ ($V_{DD} = +11.4V$ to $+15.75V$, $V_{REF} = +10V$; $V_{PIN3} = V_{PIN4} = 0V$, $V_{SS} = -300mV$. All specifications T_{min} to T_{max} unless otherwise stated)

Parameter	J, A Versions	K, B Versions	S Version	T Version	Units	Test Conditions/Comments
ACCURACY						
Resolution	14	14	14	14	Bits	All grades guaranteed monotonic over temperature. Measured using internal R_{FB} and includes effects of leakage current and gain T.C.
Relative Accuracy	± 2	± 1	± 2	± 1	LSB max	
Differential Nonlinearity	± 1	± 1	± 1	± 1	LSB max	
Full Scale Error	± 8	± 4	± 8	± 4	LSB max	
Gain Temperature Coefficient ² $\Delta\text{Gain}/\Delta\text{Temperature}$	± 5	± 2.5	± 5	± 2.5	ppm/°C max	Typical value is 0.5ppm/°C
Output Leakage Current I_{OUT} (Pin 3)						All digital inputs 0V $V_{SS} = -300mV$ $V_{SS} = 0V$
+ 25°C	± 5	± 5	± 5	± 5	nA max	
T_{min} to T_{max}	± 10	± 10	± 20	± 20	nA max	
T_{min} to T_{max}	± 25	± 25	± 150	± 150	nA max	
REFERENCE INPUT						
Input Resistance, Pin 1	3.5 10	3.5 10	3.5 10	3.5 10	k Ω min k Ω max	Typical Input Resistance = 6k Ω
DIGITAL INPUTS						
V_{IH} (Input High Voltage)	2.4	2.4	2.4	2.4	V min	$V_{IN} = 0V$ or V_{DD}
V_{IL} (Input Low Voltage)	0.8	0.8	0.8	0.8	V max	
I_{IN} (Input Current) + 25°C	± 1	± 1	± 1	± 1	μA max	
T_{min} to T_{max}	± 10	± 10	± 10	± 10	μA max	
C_{IN} (Input Capacitance) ³	7	7	7	7	pF max	
POWER SUPPLY						
V_{DD} Range	11.4/15.75	11.4/15.75	11.4/15.75	11.4/15.75	V min/V max	Specifications guaranteed over this range. All digital inputs V_{IL} or V_{IH} All digital inputs 0V or V_{DD}
V_{SS} Range	-200/-500	-200/-500	-200/-500	-200/-500	mV min/mV max	
I_{DD}	3	3	3	3	mA max	
	500	500	500	500	μA max	

These characteristics are included for Design Guidance only and are not subject to test. ($V_{REF} = +10V$, $V_{PIN3} = V_{PIN4} = 0V$, $V_{SS} = -300mV$, Output Amplifier is AD544 except where stated).

AC PERFORMANCE CHARACTERISTICS

Parameter	$V_{DD} = +11.4V$ to $+15.75V$ $T_A = 25^\circ C$ $T_A = T_{min}$ to T_{max}		Units	Test Conditions/Comments
Output Current Settling Time	1.5	—	μs max	To 0.003% of full scale range. I_{OUT} load = 100 Ω , $C_{EXT} = 13pF$. DAC register alternately loaded with all 1's and all 0's. Typical value of Settling Time is 0.8 μs .
Digital to Analog Glitch Impulse	100	—	nV-sec typ	Measured with $V_{REF} = 0V$. I_{OUT} load = 100 Ω , $C_{EXT} = 13pF$. DAC register alternately loaded with all 1's and all 0's.
Multiplying Feedthrough Error ⁴	3	5	mV p-p typ	$V_{REF} = \pm 10V$, 10kHz sine wave DAC register loaded with all 0's.
Power Supply Rejection $\Delta\text{Gain}/\Delta V_{DD}$	± 0.01	± 0.02	% per % max	$\Delta V_{DD} = \pm 5\%$
Output Capacitance C_{OUT} (Pin 3)	260	260	pF max	DAC register loaded with all 1's
C_{OUT} (Pin 3)	130	130	pF max	DAC register loaded with all 0's
Output Noise Voltage Density (10Hz – 100kHz)	15	—	nV/ $\sqrt{Hz}$ typ	Measured between R_{FB} and I_{OUT}

NOTES

¹Temperature range as follows: J, K Versions: 0 to +70°C

A, B Versions: -25°C to +85°C

S, T Versions: -55°C to +125°C

²Specifications are guaranteed for a V_{DD} of +11.4V to +15.75V. At $V_{DD} = 5V$, the device is fully functional with degraded specifications.

³Guaranteed by Product Assurance testing.

⁴Feedthrough can be further reduced by connecting the metal lid on the ceramic package to DGND.

Specifications subject to change without notice.

TIMING CHARACTERISTICS¹ ($V_{DD} = +11.4V$ to $+15.75V$, $V_{REF} = +10V$, $V_{FDD} = V_{FDD} = 0V$, $V_{SS} = -300mV$)

Parameter	Limit at $T_A = 25^\circ C$	Limit at $T_A = 0$ to $+70^\circ C$ $T_A = -25^\circ C$ to $+85^\circ C$	Limit at $T_A = -55^\circ C$ to $+125^\circ C$	Units	Test Conditions/Comments
t_1	0	0	0	ns min	Address Valid to Write Setup Time
t_2	0	0	0	ns min	Address Valid to Write Hold Time
t_3	140	160	180	ns min	Data Setup Time
t_4	20	20	30	ns min	Data Hold Time
t_5	0	0	0	ns min	Chip Select to Write Setup Time
t_6	0	0	0	ns min	Chip Select to Write Hold Time
t_7	170	200	240	ns min	Write Pulse Width

NOTES

¹Temperature range as follows: J, K Versions: 0 to $+70^\circ C$
A, B Versions: $-25^\circ C$ to $+85^\circ C$
S, T Versions: $-55^\circ C$ to $+125^\circ C$

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ C$ unless otherwise stated)

V_{DD} (Pin 19) to DGND	$-0.3V$, $+17V$
V_{SS} (Pin 20) to AGND	$-15V$, $+0.3V$
V_{REF} (Pin 1) to AGND	$\pm 25V$
V_{RFB} (Pin 2) to AGND	$\pm 25V$
Digital Input Voltage (Pins 7–18) to DGND	$-0.3V$, V_{DD}
V_{PIN3} to DGND	$-0.3V$, V_{DD}
AGND to DGND	$-0.3V$, V_{DD}
Power Dissipation (Any Package)	
To $+75^\circ C$	450mW
Derates above $+75^\circ C$	6mW/ $^\circ C$

Operating Temperature Range

Commercial (J, K Versions)	0 to $+70^\circ C$
Industrial (A, B Versions)	$-25^\circ C$ to $+85^\circ C$
Extended (S, T Versions)	$-55^\circ C$ to $+125^\circ C$
Storage Temperature	$-65^\circ C$ to $+150^\circ C$
Lead Temperature (Soldering, 10secs)	$+300^\circ C$

*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are inserted.



ORDERING GUIDE

Model	Temperature Range	Relative Accuracy	Full Scale Error	Package Option*
AD7534JN	$0^\circ C$ to $+70^\circ C$	$\pm 2LSB$	$\pm 8LSB$	N-20
AD7534KN	$0^\circ C$ to $+70^\circ C$	$\pm 1LSB$	$\pm 4LSB$	N-20
AD7534JP	$0^\circ C$ to $+70^\circ C$	$\pm 2LSB$	$\pm 8LSB$	P-20A
AD7534KP	$0^\circ C$ to $+70^\circ C$	$\pm 1LSB$	$\pm 4LSB$	P-20A
AD7534AQ	$-25^\circ C$ to $+85^\circ C$	$\pm 2LSB$	$\pm 8LSB$	Q-20
AD7534BQ	$-25^\circ C$ to $+85^\circ C$	$\pm 1LSB$	$\pm 4LSB$	Q-20
AD7534SQ	$-55^\circ C$ to $+125^\circ C$	$\pm 2LSB$	$\pm 8LSB$	Q-20
AD7534TQ	$-55^\circ C$ to $+125^\circ C$	$\pm 1LSB$	$\pm 4LSB$	Q-20

*N = Plastic DIP; P = Plastic Leaded Chip Carrier; Q = Cerdip.

AD7534

TERMINOLOGY

RELATIVE ACCURACY

Relative accuracy or endpoint nonlinearity is a measure of the maximum deviation from a straight line passing through the endpoints of the DAC transfer function. It is measured after adjusting for zero error and full scale error and is normally expressed in Least Significant Bits or as a percentage of full scale reading.

DIFFERENTIAL NONLINEARITY

Differential nonlinearity is the difference between the measured change and the ideal 1LSB change between any two adjacent codes. A specified differential nonlinearity of $\pm 1\text{LSB}$ max over the operating temperature range ensures monotonicity.

FULL-SCALE ERROR

Full scale error or gain error is a measure of the output error between an ideal DAC and the actual device output. Full scale error is adjustable to zero with an external potentiometer.

DIGITAL TO ANALOG GLITCH IMPULSE

The amount of charge injected from the digital inputs to the analog output when the inputs change state. This is normally specified as the area of the glitch in either pA-secs or nV-secs depending upon whether the glitch is measured as a current or voltage. The measurement takes place with $V_{\text{REF}} = \text{AGND}$.

OUTPUT CAPACITANCE

Capacitance from I_{OUT} to AGND.

OUTPUT LEAKAGE CURRENT

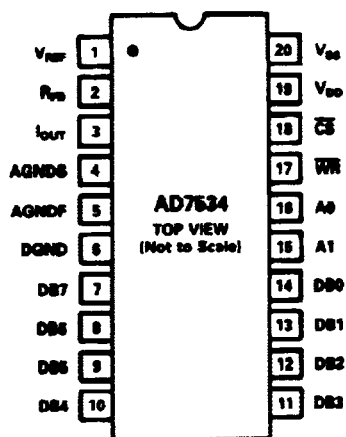
Current which appears at I_{OUT} with the DAC register loaded to all 0's.

MULTIPLYING FEEDTHROUGH ERROR

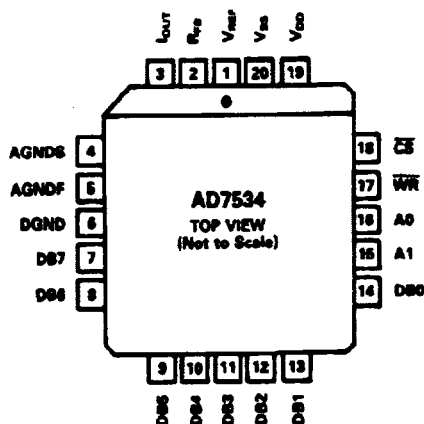
AC error due to capacitive feedthrough from V_{REF} terminal to I_{OUT} with DAC register loaded to all zeros.

PIN CONFIGURATIONS

DIP



PLCC



Pin Function Description — AD7534

Pin	Function	Description
1	V_{REF}	Reference Input Voltage
2	R_{FB}	Feedback resistor. Used to close the loop around an external op-amp.
3	I_{OUT}	Current Output Terminal
4	AGNDS	Analog ground sense line. Reference point for external circuitry. This pin should carry minimal current.
5	AGNDF	Analog ground force line; carries current from internal analog ground connections. AGNDF and AGNDS are tied together internally.
6	DGND	Digital Ground
7	DB7	Data Bit 7
8	DB6	Data Bit 6
9	DB5	Data Bit 5 or Data Bit 13 (DAC MSB)
10	DB4	Data Bit 4 or Data Bit 12
11	DB3	Data Bit 3 or Data Bit 11
12	DB2	Data Bit 2 or Data Bit 10
13	DB1	Data Bit 1 or Data Bit 9
14	DB0	Data Bit 0 or Data Bit 8
15	A1	Address line 1
16	A0	Address line 0
17	$\overline{WR}$	Write input. Active low.
18	$\overline{CS}$	Chip Select Input. Active low.

$\overline{WR}$	$\overline{CS}$	A1	A0	Function
X ¹	1	X	X	Device not selected
1	X	X	X	No data transfer
0	0	0	0	DAC loaded directly from Data Bus ²
0	0	0	1	MS Input Register loaded from Data Bus
0	0	1	0	LS Input Register loaded from Data Bus
0	0	1	1	DAC Register loaded from Input Registers.

NOTES

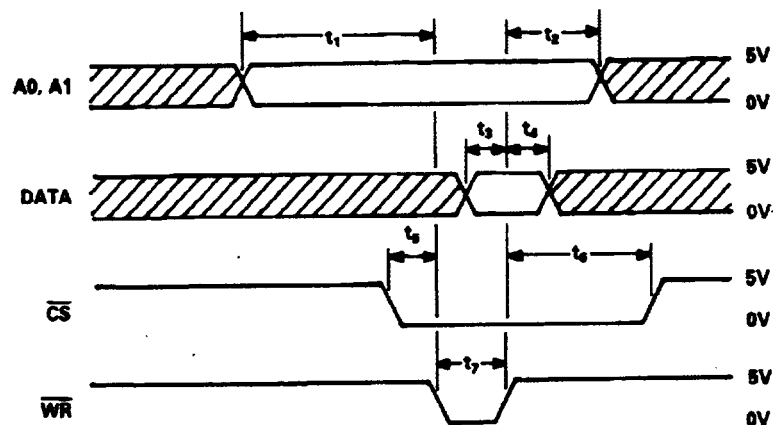
1. X = Don't Care

2. When $A_1 = 0$, $A_0 = 0$ all DAC registers are transparent, so by placing all 0's or all 1's on the data inputs the user can load the DAC to zero or full scale output in one write operation. This facility simplifies system calibration.

+12V to +15V supply input.

Bias pin for High Temperature Low Leakage configuration. To implement low leakage system, the pin should be at a negative voltage. See Figures 4, 5 or 6 for recommended circuitry.

19 V_{DD}
20 V_{SS}



NOTES

1. ALL INPUT SIGNAL RISE AND FALL TIMES MEASURED FROM 10% TO 90% OF +5V. $t_r = t_f = 20\text{ns}$.

2. TIMING MEASUREMENT REFERENCE LEVEL IS $\frac{V_{OH} + V_{OL}}{2}$

Figure 1. AD7534 Timing Diagram

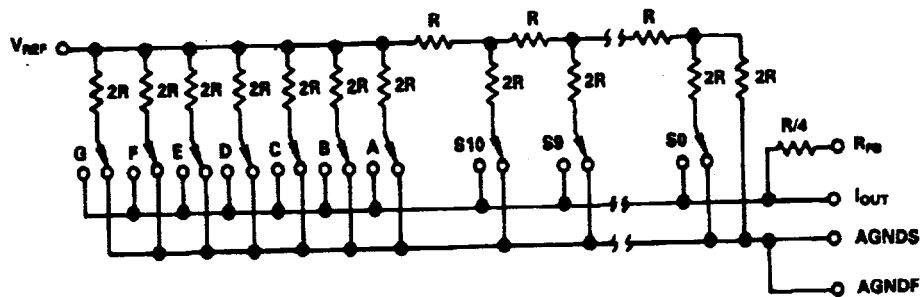


Figure 2. Simplified Circuit Diagram for the AD7534 D/A Section

CIRCUIT INFORMATION - D/A SECTION

Figure 2 shows a simplified circuit diagram for the AD7534 D/A section. The three MSB's of the 14-bit Data Word are decoded to drive the seven switches A-G. The 11 LSB's of the Data Word drive an inverted R-2R ladder which steers the binary weighted current available to it between I_{OUT} and AGNDF.

If I is taken as the input current at V_{REF} the input current to the R-2R ladder is $1/8$. $7/8 I$ flows in the parallel ladder structure. Switches A-G steer binary weighted current between I_{OUT} and AGNDF.

The input resistance at V_{REF} is constant and may be driven by a voltage source or a current source of positive or negative polarity.

EQUIVALENT CIRCUIT ANALYSIS

Figure 3 shows an equivalent circuit for the analog section of the AD7534 D/A converter. The current source $I_{LEAKAGE}$ is composed of surface and junction leakages. The resistor R_O denotes the equivalent output resistance of the DAC which varies with input code. C_{OUT} is the capacitance due to the current steering switches and varies from about 90pF to 180pF (typical values) depending upon the digital input. $g(V_{REF}, N)$ is the Thevenin equivalent voltage generator due to the reference

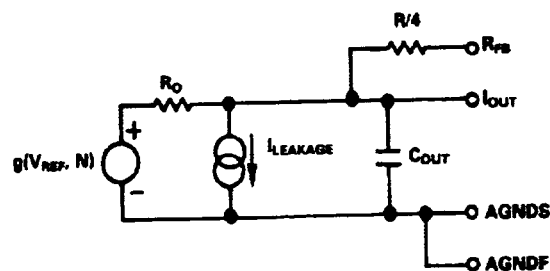


Figure 3. AD7534 Equivalent Analog Output Circuit

input voltage, V_{REF} , and the transfer function of the R-2R ladder, N .

CIRCUIT INFORMATION - DIGITAL SECTION

The digital inputs are designed to be both TTL and 5V CMOS compatible. All logic inputs are static protected MOS gates with typical input currents of less than 1nA. Internal input protection is achieved by an on-chip distributed diode from DGND to each MOS gate. To minimize power supply currents, it is recommended that the digital input voltages be driven as close as possible to 0 and 5V logic levels.

UNIPOLAR BINARY OPERATION (2-QUADRANT MULTIPLICATION)

Figure 4 shows the circuit diagram for unipolar binary operation. With an ac input, the circuit performs 2-quadrant multiplication. The code table for Figure 4 is given in Table I.

Capacitor C1 provides phase compensation and helps prevent overshoot and ringing when high speed op-amps are used.

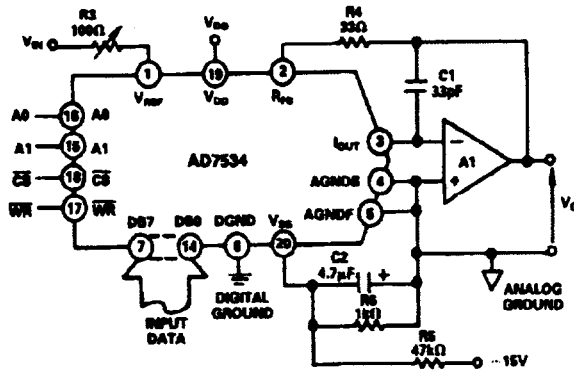


Figure 4. Unipolar Binary Operation

Binary Number In DAC Register		Analog Output, V_{OUT}
MSB	LSB	
11	1111 1111 1111	$-V_{IN} \left(\frac{16383}{16384} \right)$
10	0000 0000 0000	$-V_{IN} \left(\frac{8192}{16384} \right) = -1/2 V_{IN}$
00	0000 0000 0001	$-V_{IN} \left(\frac{1}{16384} \right)$
00	0000 0000 0000	0V

Table I. Unipolar Binary Code Table for AD7534

ZERO OFFSET AND GAIN ADJUSTMENT FOR FIGURE 4.

Calibration codes for zero and full scale adjust (all 0's, all 1's) can be loaded in one write operation (see Pin Function Description).

Zero Offset Adjustment

1. Load DAC register with all 0's.
2. Adjust offset of amplifier A1 so that V_O is at a minimum (i.e., $\leq 30\mu V$).

Gain Adjustment

1. Load DAC register with all 1's.
2. Trim potentiometer R3 so that $V_O = -V_{IN} \left(\frac{16383}{16384} \right)$

In fixed reference applications full scale can also be adjusted by omitting R3 and R4 and trimming the reference voltage magnitude.

For high temperature applications, resistors and potentiometers should have a low Temperature Coefficient. In many applications, because of the excellent Gain T.C. and Gain Error specifications of the AD7534, Gain Error trimming is not necessary.

BIPOLAR OPERATION (4-QUADRANT MULTIPLICATION)

The recommended circuit diagram for bipolar operation is shown in Figure 5. Offset binary coding is used.

With the DAC loaded to 10 0000 0000 0000, adjust R3 for $V_O = 0V$. Alternatively, one can omit R3 and R4 and adjust the ratio of R7 and R8 for $V_O = 0V$. Full scale trimming can be accomplished by adjusting the amplitude of V_{IN} or by varying the value of R9.

Resistors R7, R8 and R9 should be matched to 0.003%. Mismatch of R7 and R8 causes both offset and full scale error. When operating over a wide temperature range, it is important that the resistors be of the same type so that their temperature coefficient match.

The code table for Figure 5 is given in Table II.

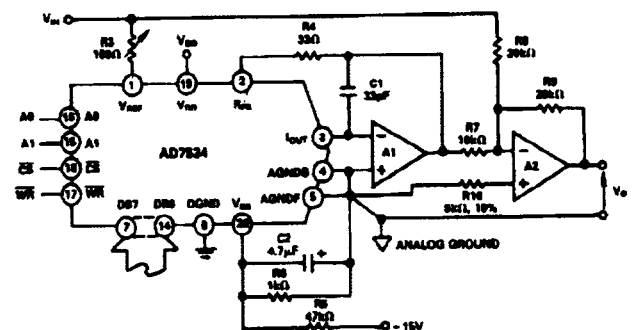


Figure 5. Bipolar Operation

Binary Number in DAC Register		Analog Output
MSB	LSB	
11	1111 1111 1111	$+V_{IN} \left(\frac{8191}{8192} \right)$
10	0000 0000 0001	$+V_{IN} \left(\frac{1}{8192} \right)$
10	0000 0000 0000	0
01	1111 1111 1111	$-V_{IN} \left(\frac{1}{8192} \right)$
00	0000 0000 0000	$-V_{IN} \left(\frac{8192}{8192} \right)$

Table II. Bipolar Code Table for Offset Binary Circuit of Figure 5.

AD7534

GROUNDING TECHNIQUES

Since the AD7534 is specified for high accuracy, it is important to use a proper grounding technique. The two AGND pins (AGNDF and AGNDS) provide flexibility in this respect. In Figure 4, AGNDS and AGNDF are externally shorted and A2 is not used. Voltage drops due to bond wire resistances are not compensated for in this circuit. This means that an extra linearity error of less than 0.1LSB is added to the DAC linearity error. If the user wishes to eliminate this extra error, then the circuit of Figure 6 should be used. Here, A2 is used to maintain AGNDS

at Signal Ground potential. By using the Force, Sense technique all switch contacts on the DAC are at exactly the same potential and any error due to bond wire resistance is eliminated.

Figure 7 shows a Printed Circuit Board layout for the AD7534 with a single output amplifier. The input to V_{REF} (pin 1) is shielded to reduce ac feedthrough while the digital inputs are shielded to minimize digital feedthrough. The tracks connecting I_{OUT} and AGNDS to the inverting and noninverting op amp inputs are kept as short as possible. Gain trim components, R3 and R4, have been omitted.

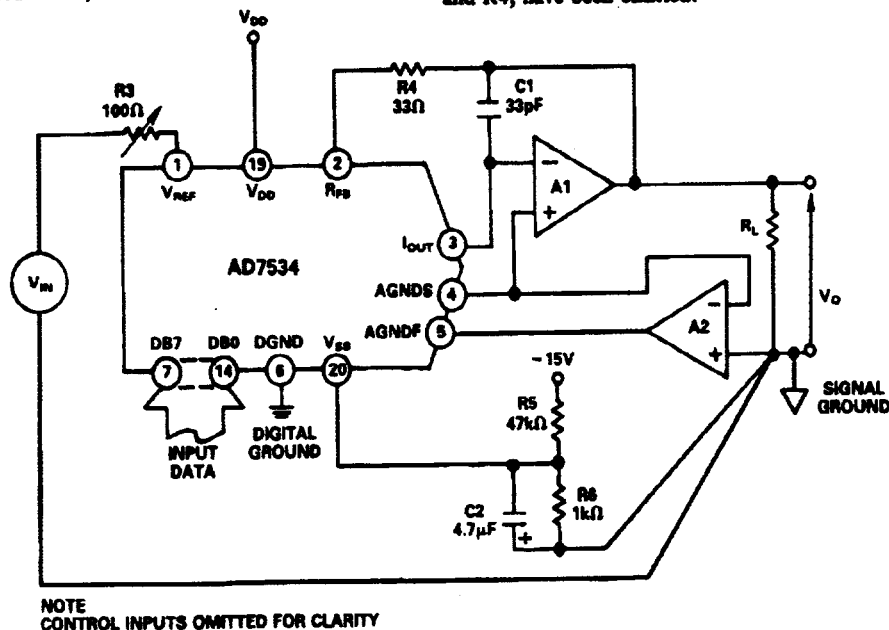


Figure 6. Unipolar Binary Operation with Forced Ground

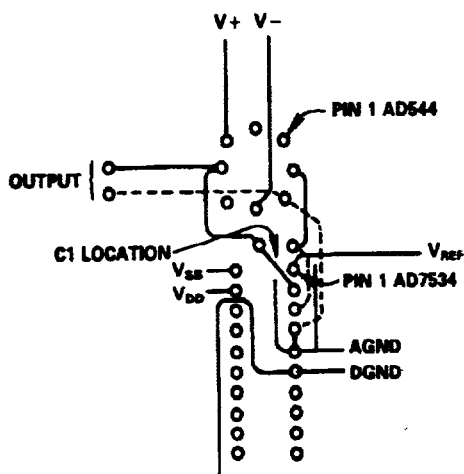


Figure 7. Suggested Layout for AD7534 Incorporating Output Amplifier

ZERO OFFSET AND GAIN ADJUSTMENT FOR FIGURE 6

Zero Offset Adjustment

1. Load DAC register with all 0's.
2. Adjust offset of amplifier A2 for minimum potential at AGNDS. This potential should be $\leq 30\mu V$ with respect to Signal Ground.
3. Adjust offset of amplifier A1 so that V_O is at a minimum (i.e. $\leq 30\mu V$).

Gain Adjustment

1. Load DAC register with all 1's.
2. Trim potentiometer R3 so that $V_O = -V_{IN} \left(\frac{16383}{16384} \right)$

LOW LEAKAGE CONFIGURATION

For CMOS Multiplying D/A converters, as the device is operated at higher temperatures the output leakage current increases. For a 14-bit resolution system, this can be a significant source of error. The AD7534 features a leakage reduction configuration to keep the leakage current low over an extended temperature range. One may operate the device with or without this configuration. If V_{SS} (pin 20) is tied to AGND then the DAC will exhibit normal output leakage current at high temperatures. To use the low leakage facility, V_{SS} should be tied to a voltage of approximately $-0.3V$ as in Figures 4, 5 and 6. A simple resistor divider (R_5 , R_6) produces $-312mV$ from $-15V$. The capacitor C_2 in parallel with R_6 is an integral part of the low leakage configuration and must be $4.7\mu F$ or greater. Figure 8 is a plot of leakage current versus temperature for both conditions. It clearly shows the improvement gained by using the low leakage configuration.

OP AMP SELECTION

In choosing an amplifier to be used with the AD7534, three

parameters are of prime importance. These are Input Offset Voltage (V_{OS}), Input Bias Current, (I_{BIAS}) and Offset Voltage Drift. To maintain specified accuracy with V_{REF} at $10V$, V_{OS} must be less than $30\mu V$ while I_{BIAS} should be less than $2nA$. Also the open loop gain of the amplifier must be sufficiently high to keep $V_{OS} \leq 30\mu V$ for the full output voltage range. Thus for a max output of $10V$, A_{VOL} must be greater than $340,000$.

An amplifier with low offset voltage drift is required to give the desired system accuracy over an operating temperature range.

At low frequencies the AD OP-07 satisfies the above requirements and in most cases will not need an offset adjust potentiometer.

For high frequency operation, one may use a wide bandwidth amplifier such as the AD544 or the LF356 with either an offset adjust potentiometer or automatic nulling circuitry.

The choice of amplifier depends entirely on the required system accuracy, the required temperature range, and the operating frequency.

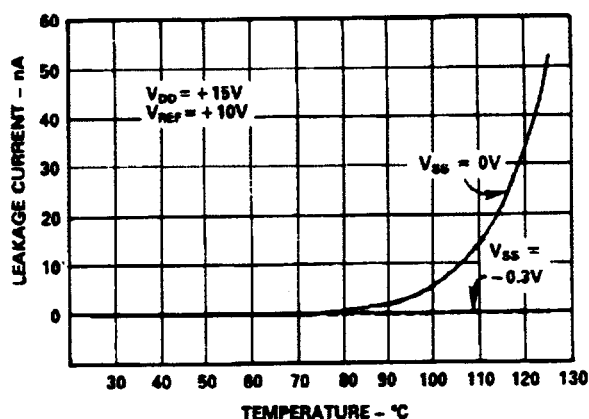


Figure 8. Graph of Typical Leakage Current vs. Temperature for AD7534

AD7534

MICROPROCESSOR INTERFACING

AD7534 - 8085A INTERFACE

A typical interface circuit for the AD7534 and the 8085A microprocessor is given in Figure 9. The microprocessor sees the DAC as four memory locations, identified by address lines A0, A1. In standard operation, three of these memory locations are used. A sample program for loading the DAC with a 14-bit word is given in Table III. The AD7534 has address locations 3000-3003.

The six MSBs are written into location 3001, and the eight LSBs are written to 3002. Then with a write instruction to 3003

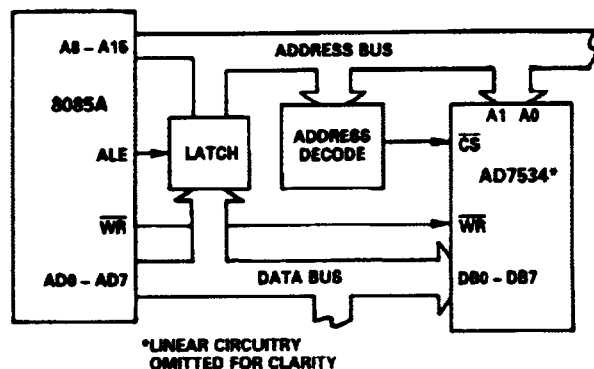


Figure 9. AD7534 - 8085A Interface

the full 14-bit word is loaded to the DAC register and the analog equivalent appears at the output.

AD7534 - 8086 INTERFACE

The AD7534 may be interfaced to the 16-bit 8086 microprocessor using the circuit of Figure 10. The bottom 8 bits (AD0-AD7) of the 16-bit data bus are connected to the DAC data bus. The 14-bit word is loaded in two bytes using the MOV instruction. A further MOV loads the DAC register and causes the analog data to appear at the converter output. For the example given here, the appropriate DAC register addresses are D002, D004, D006. The program for loading the DAC is given below in Table IV.

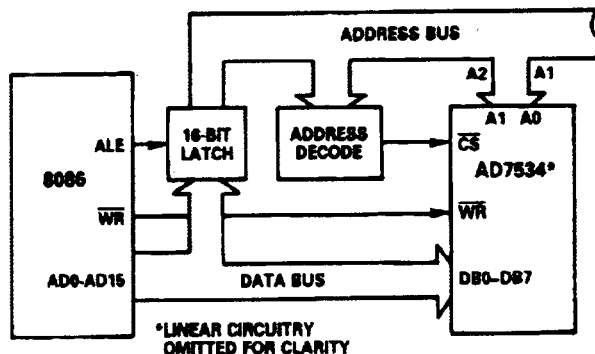


Figure 10. AD7534 - 8086 Interface Circuit

Address	Op-Code	Mnemonic
2000	26	MV IH, # 30
01	30	
02	2E	MV IL, # 01
03	01	
04	3E	MV IA, # "MS"
05	"MS"	
06	77	MOV M, A
07	2C	INR L
08	3E	MV IA, # "LS"
09	"LS"	
0A	77	MOV M, A
0B	2C	INR L
0C	77	MOV M, A
200D	CF	RST I

Table III. Program Listing for Figure 9

ASSUME DS: DACLOAD, CS : DACLOAD
DACLOAD SEGMENT AT 000

00	8CC9	MOV CX, CS	: DEFINE DATA SEGMENT REGISTER EQUAL
02	8ED9	MOV DS, CX	: TO CODE SEGMENT REGISTER
04	BF02D0	MOV DI, # D002	: LOAD DI WITH D002
07	C605"MS"	MOV MEM, # "MS"	: MS INPUT REGISTER LOADED WITH "MS"
0A	47	INC DI	
0B	47	INC DI	
0C	C605"LS"	MOV MEM, # "LS"	: LS INPUT REGISTER LOADED WITH "LS"
0F	47	INC DI	
10	47	INC DI	
11	C60500	MOV MEM, # 00	: CONTENTS OF INPUT REGISTERS
			: ARE LOADED TO THE DAC REGISTER.
14	EA0000	JMP MEM	: CONTROL IS RETURNED TO THE MONITOR
17	00FF		: PROGRAM

Table IV. Sample Program for Loading AD7534 from 8086

LDD Load D Accumulator from memory.
STD Store D Accumulator to memory.



The interface circuit for the 6502 microprocessor is shown in Figure 12.



Interfacing to the Z80 microprocessor requires a minimal amount of extra components. The circuit consists of the Z80 processor, the AD7534 and an address decoder for the DAC. Figure 13, below, illustrates the circuit.



AD7534 - MC68000 INTERFACE

	A2 E003		Address Register 2 is loaded with E003.
01000	MOVE.W	# W, D0	The desired DAC data, W, is loaded into Data Register 0. W may be any value between 0 and 16383 (decimal) or 0 and 3FFF (hexadecimal).
	MOVEP.W	D0,\$0000(A2)	The data W is transferred between D0 and the Input Registers of the DAC. The high order byte of data is transferred first. The memory address is specified using the address register-indirect plus displacement addressing mode. The address used in this instance (B003) is odd and no data is transferred on the low order half of the data bus (D0-D7).
	MOVE.W	D0,\$E006	This instruction provides appropriate signals to transfer the data W from the DAC Input Registers to the DAC Register, which controls the switches in the 14-bit D/A structure.
	MOVE.B	# 228,D7	Control is returned to the System Monitor Program using these two instructions.
	TRAP	# 14	

DIGITAL FEEDTHROUGH

In the preceding interface configurations, most digital inputs to the AD7534 are directly connected to the microprocessor bus. Even when the device is not selected, these inputs will be constantly changing. The high frequency logic activity on the bus can feed through the DAC package capacitance to show up as noise on

[illegible]

Figure 14. AD7534 – MC68000 Interface

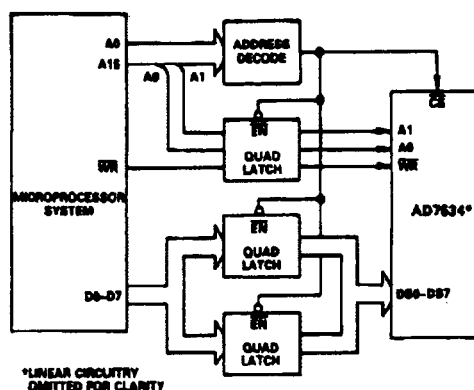


Figure 15. AD7534 Interface Circuit Using Latches to Minimize Digital Feedthrough

Dimensions shown in inches and (mm).

20-PIN CERAMIC DIP (SUFFIX D)

Top View Dimensions:

- Overall Width: 0.290 ± 0.005 (7.37 $\pm$ 0.254)
- Overall Length: 1.000 ± 0.010 (25.40 $\pm$ 0.254)

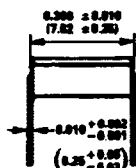
Side View Dimensions:

- Pin Pitch: 0.070 ± 0.002 (1.78 $\pm$ 0.051) TYP
- Pin Length: 0.100 ± 0.005 (2.54 $\pm$ 0.127)
- Body Height: 0.085 ± 0.005 (2.16 $\pm$ 0.254)
- Pin Spacing (Pitch): 0.500 ± 0.005 (12.70 $\pm$ 0.127) TYP

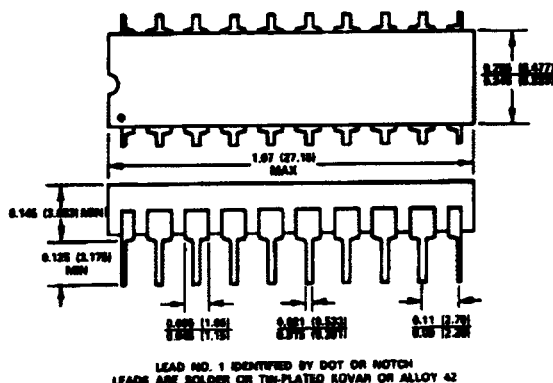
NOTES:

1. DIMENSIONS ARE IN INCHES AND MILLIMETERS.
2. FINISHES: CERAMIC BODY, METAL PLATING.
3. TYPICAL VALUES ARE IN PARENTHESES.

NOTES:
1. LEAD NUMBER 1 IDENTIFIED BY DOT OR NOTCH.
2. LEADS WILL BE EITHER GOLD OR TIN PLATED IN ACCORDANCE WITH MIL-26-38010 REQUIREMENTS.



20-PIN PLASTIC DIP (SUFFIX N)



LEAD NO. 1 IDENTIFIED BY DOT OR NOTCH
LEADS ARE SOLDER OR TIN-PLATED COPPER OR ALLOY 42

